

1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

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WeEn Semiconductors





Product data sheet

1. General description

Planar passivated AC Thyristor Triac power switch in a SOT186A (TO-220F) "full pack" plastic package with self-protective capabilities against low and high energy transients. This triac will commutate the full RMS current at the maximum rated junction temperature $(T_{j(max)} = 150 \text{ °C})$ without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

2. Features and benefits

- Clamping structure ensuring safe high over-voltage withstand capability
- High junction operating temperature capability
- Full cycle AC conduction
- Isolated mounting base package
- Less sensitive gate for high noise immunity
- Over-voltage withstand capability to IEC 61000-4-5
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- Safe clamping capability for low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls
- Applications subject to high temperature

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	800	V
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$	-	-	120	A
Tj	junction temperature		-	-	150	°C





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Symbol	Parameter	Conditions	Mir	п Тур	Max	Unit
I _{T(RMS)}	RMS on-state current	full sine wave; $T_h \le 83 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	-	-	12	A
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; Fig. <u>6</u>	-	-	2	kV
Static char	acteristics	· · · · ·	I			
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
		V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	85	D –	-	V
Dynamic cl	haracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	50	0 -	-	V/µs
dI _{com} /dt	rate of change of commutating current	$\label{eq:VD} \begin{split} V_D &= 400 \text{ V}; \text{T}_{j} = 150 ^\circ\text{C}; \text{I}_{\text{T}(\text{RMS})} = 12 \text{ A}; \\ dV_{\text{com}}/dt &= 20 \text{V}/\mu\text{s}; (\text{snubberless} \\ \text{condition}); \text{ gate open circuit} \end{split}$	5	-	-	A/ms

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	T2-71
2	T2	main terminal 2		Sym051
3	G	gate		
mb	n.c.	mounting base; isolated		
			TO-220F (SOT186A)	

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6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
ACTT12X-800CT	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A			

7. Marking

Table 4. Marking codes	
Type number	Marking code
ACTT12X-800CT	ACTT12X-800CT

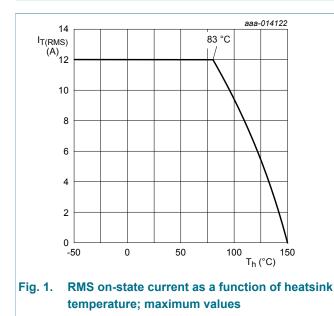
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8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_h \le 83 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	-	12	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$	-	120	A
		full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$	-	132	A
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	72	A ² s
dl _T /dt	rate of rise of on-state current	I_{T} = 12 A; I_{G} = 0.2 A; dI_{G}/dt = 0.2 A/µs	-	100	A/µs
I _{GM}	peak gate current	t = 20 μs	-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; Fig. 6	-	2	kV



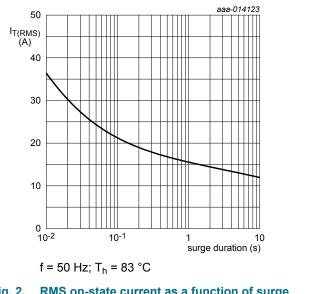
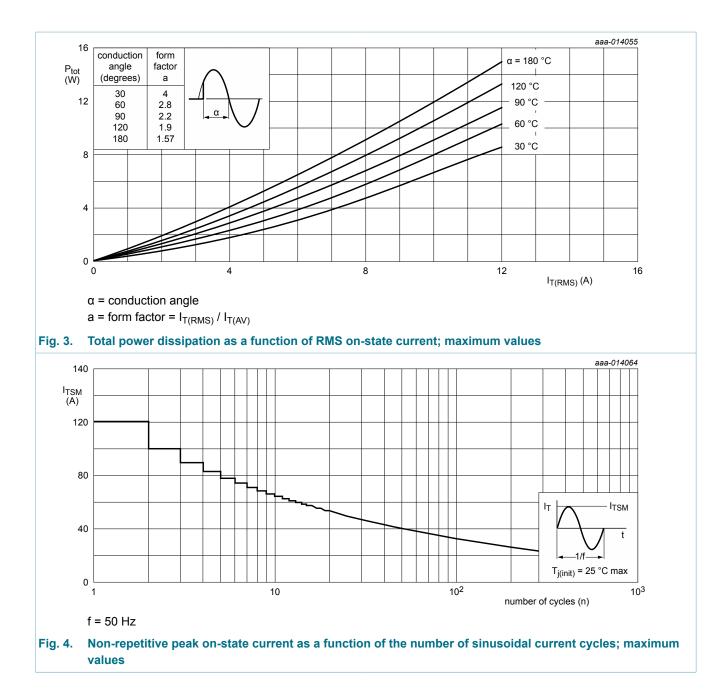


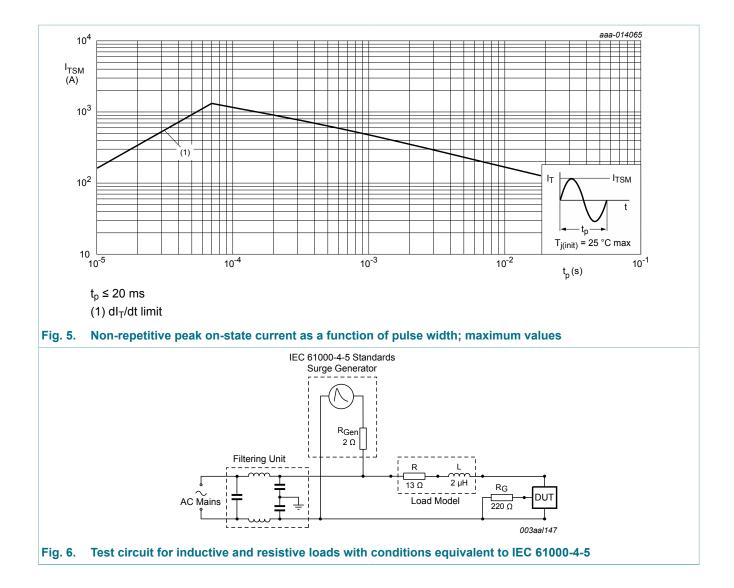
Fig. 2. RMS on-state current as a function of surge duration; maximum values

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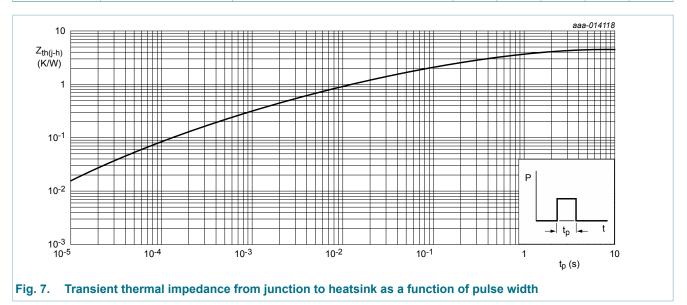
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9. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to heatsink	full cycle; with heatsink compound; Fig. 7		-	-	4.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		-	55	-	K/W



10. Isolation characteristics

Table 7. Isolation characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V _{isol(RMS)}	RMS isolation voltage	50 Hz \leq f \leq 60 Hz; RH \leq 65% RH; T _h = 25 °C; from all terminals to external heatsink; sinusoidal waveform; clean and dust free		-	-	2500	V	
C _{isol}	isolation capacitance	f = 1 MHz; T _h = 25 °C; from main terminal 2 to external heatsink		-	10	-	pF	

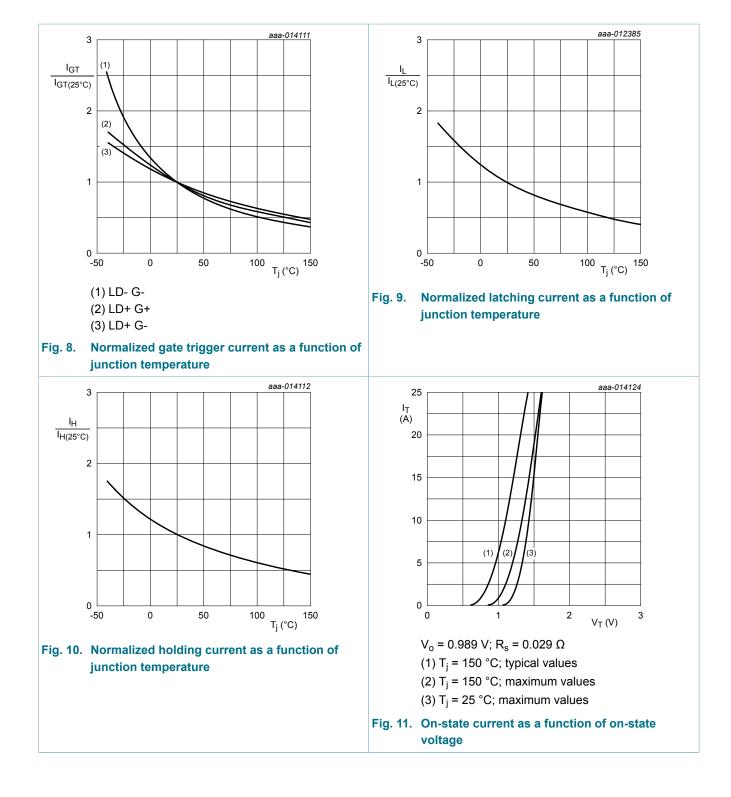
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11. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · · · · · · · · · · · · · · · · ·				
I _{GT}	gate trigger current	V_D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; Fig. 8	-	-	35	mA
		V_D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; Fig. 8	-	-	35	mA
		V_D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
IL	latching current	V_D = 12 V; I _G = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA
		V_D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	70	mA
		V_D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; Fig. 9	-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	50	mA
V _T	on-state voltage	I _T = 17 A; T _j = 25 °C; <u>Fig. 11</u>	-	1.25	1.5	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 100 mA; T _j = 25 °C; Fig. 12	-	0.8	1	V
		V _D = 400 V; I _T = 100 mA; T _j = 150 °C; Fig. 12	0.2	0.45	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _j = 150 °C	-	-	0.5	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic cl	naracteristics	· · ·	I	I		
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	V_D = 400 V; T_j = 150 °C; $I_{T(RMS)}$ = 12 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit	5	-	-	A/ms

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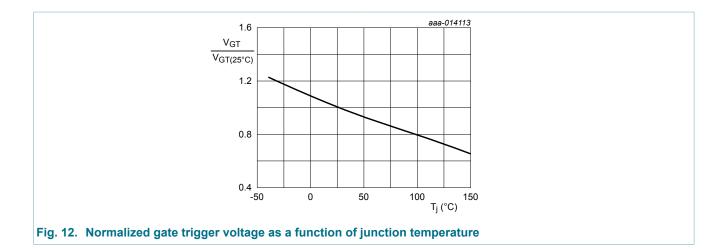


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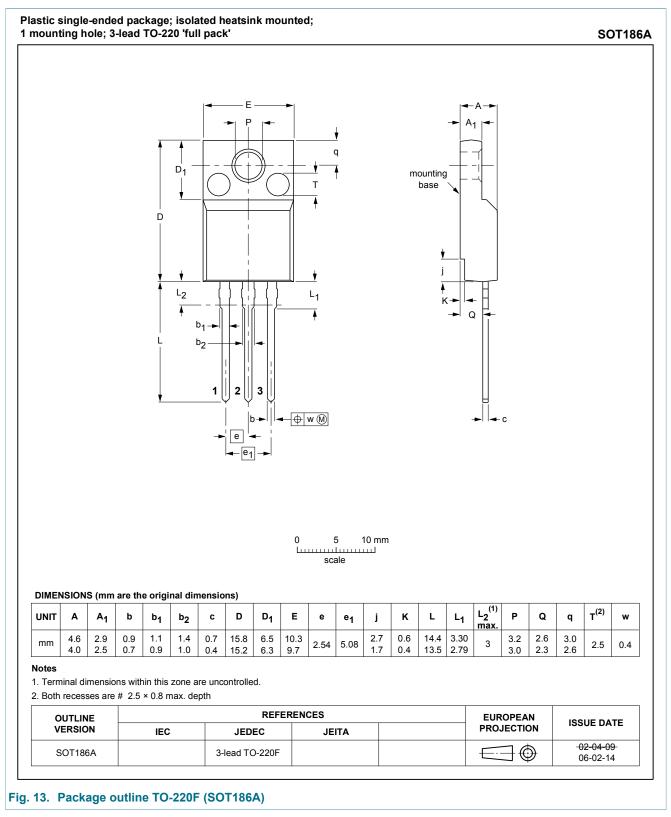
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12. Package outline



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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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